

Atty. Dkt. No. AMAT/3421.C1/ISM/COPPER/DV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	Application of:	
	CI.	/1

Serial No.:

Filed:

For:

Apparatus for Electro Chemical

Deposition of Copper Metallization

With the Capability of In-Situ

Thermal Annealing

Group Art Unit:

Examiner:

Assistant Commissioner for Patents

Washington, D.C. 20231

Dear Sir:

CERTIFICATE OF MAILING

37 C.F.R. 1.10

I hereby certify that this correspondence is being deposited on 2000, with the United States Postal Service as Express Mail No. EL635441628US, in an envelope addressed to: Assistant Commissioner for Patents, Box PATENT APPLICATION, Washington, D.C. 20231.

PRELIMINARY AMENDMENT

Applicants request entry of the following amendments prior to consideration of the claims pending in the application.

IN THE CLAIMS:

Please amend the claims as follows:

(Amended) | An electro-chemical deposition system, comprising:

- a mainframe having a mainframe wafer transfer robot; a)
- a loading station disposed in connection with the mainframe;
- one or more [processing] electrochemical deposition cells disposed in connection

with the mainframe; and

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